

DIODE MODULE

DD(KD)30GB40/80

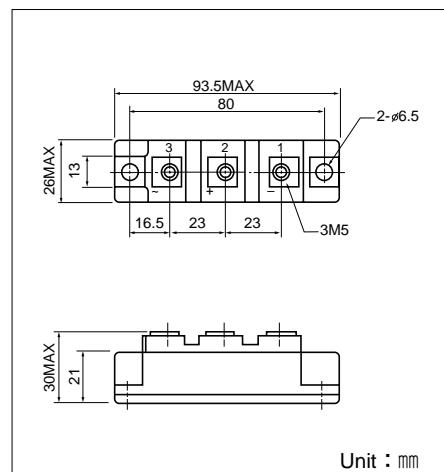
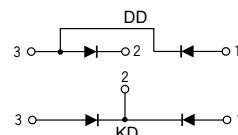
UL;E76102(M)

Power Diode Module **DD30GB** series are designed for various rectifier circuits. **DD30GB** has two diode chips connected in series and the mounting base is electrically isolated from elements for simple heatsink construction. Wide voltage rating up to, 800V is available for various input voltage.

- Isolated mounting base
- Two elements in a package for simple (single and three phase) bridge connections
- Highly reliable glass passivated chips
- High surge current capability

(Applications)

Various rectifiers, Battery chargers, DC motor drives



■ Maximum Ratings

($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Item	Ratings		Unit
		DD30GB40	DD30GB80	
V_{RRM}	Repetitive Peak Reverse Voltage	400	800	V
V_{RSM}	Non-Repetitive Peak Reverse Voltage	480	960	V

Symbol	Item	Conditions	Ratings	Unit
$I_F(AV)$	Average Forward Current	Single phase, half wave, 180° conduction, $T_c : 118^\circ\text{C}$	30	A
$I_F(RMS)$	R.M.S. Forward Current	Single phase, half wave, 180° conduction, $T_c : 118^\circ\text{C}$	47	A
I_{FSM}	Surge Forward Current	$\frac{1}{2}$ cycle, 50/60Hz, peak value, non-repetitive	550/600	A
I^2t	I^2t	Value for one cycle of surge current	1500	A^2s
T_j	Junction Temperature		-40 to +150	$^\circ\text{C}$
T_{stg}	Storage Temperature		-40 to +125	$^\circ\text{C}$
V_{iso}	Isolation Breakdown Voltage (R.M.S.)	A.C.1 minute	2500	V
T	Mounting	Recommended Value 2.5-3.9 (25-40)	4.7 (48)	$\text{N}\cdot\text{m}$ (kgf·cm)
	Torque	Recommended Value 1.5-2.5 (15-25)	2.7 (28)	
	Mass		170	g

■ Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
I_{RRM}	Repetitive Peak Reverse Current, max.	at V_{DRM} , single phase, half wave. $T_j=150^\circ\text{C}$	10	mA
V_{FM}	Forward Voltage Drop, max.	Forward current 90A, $T_j=25^\circ\text{C}$, Inst. measurement	1.40	V
$R_{th(j-c)}$	Thermal Impedance, max.	Junction to case	0.80	$^\circ\text{C}/\text{W}$

